Functional Safety Information LM5158-Q1 and LM51581-Q1 Functional Safety FIT Rate, FMD and Pin FMA

TEXAS INSTRUMENTS

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1 Overview

This document contains information for LM5158-Q1 and LM51581-Q1 (WQFN package) to aid in a functional safety system design. Information provided are:

- Functional Safety Failure In Time (FIT) rates of the semiconductor component estimated by the application of industry reliability standards
- · Component failure modes and their distribution (FMD) based on the primary function of the device
- Pin failure mode analysis (Pin FMA)

Figure 1-1 shows the device functional block diagram for reference.

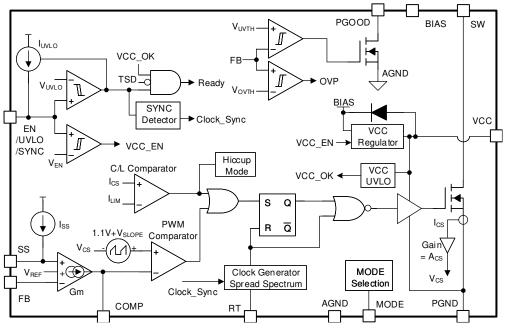


Figure 1-1. Functional Block Diagram

LM5158-Q1 and LM51581-Q1 were developed using a quality-managed development process, but were not developed in accordance with the IEC 61508 or ISO 26262 standards.



2 Functional Safety Failure In Time (FIT) Rates

This section provides Functional Safety Failure In Time (FIT) rates for LM5158-Q1 and LM51581-Q1 based on two different industry-wide used reliability standards:

- Table 2-1 provides FIT rates based on IEC TR 62380 / ISO 26262 part 11
- Table 2-2 provides FIT rates based on the Siemens Norm SN 29500-2

Table 2-1. Component Failure Rates per IEC TR 62380 / ISO 26262 Part 11

FIT IEC TR 62380 / ISO 26262	FIT (Failures Per 10 ⁹ Hours)
Total Component FIT Rate	15
Die FIT Rate	8
Package FIT Rate	7

The failure rate and mission profile information in Table 2-1 comes from the Reliability data handbook IEC TR 62380 / ISO 26262 part 11:

- Mission Profile: Motor Control from Table 11
- Power dissipation: 850 mW
- Climate type: World-wide Table 8
- Package factor (lambda 3): Table 17b
- Substrate Material: FR4
- EOS FIT rate assumed: 0 FIT

Table 2-2. Component Failure Rates per Siemens Norm SN 29500-2

Table	Category	Reference FIT Rate	Reference Virtual T _J
5	CMOS/BICMOS ASIC Analog and Mixed HV >50V supply	30 FIT	75°C

The Reference FIT Rate and Reference Virtual T_J (junction temperature) in Table 2-2 come from the Siemens Norm SN 29500-2 tables 1 through 5. Failure rates under operating conditions are calculated from the reference failure rate and virtual junction temperature using conversion information in SN 29500-2 section 4.



3 Failure Mode Distribution (FMD)

The failure mode distribution estimation for LM5158-Q1 and LM51581-Q1 in Table 3-1 comes from the combination of common failure modes listed in standards such as IEC 61508 and ISO 26262, the ratio of sub-circuit function size and complexity and from best engineering judgment.

The failure modes listed in this section reflect random failure events and do not include failures due to misuse or overstress.

Die Failure Modes	Failure Mode Distribution (%)
SW no output	40%
SW output not in specification – voltage or timing	50%
SW power low-side FET stuck on	5%
Power Good – False Trip or Failure to Trip	5%

Table 3-1. Die Failure Modes and Distribution



4 Pin Failure Mode Analysis (Pin FMA)

This section provides a Failure Mode Analysis (FMA) for the pins of the LM5158-Q1 and LM51581-Q1. The failure modes covered in this document include the typical pin-by-pin failure scenarios:

- Pin short-circuited to Ground (see Table 4-2)
- Pin open-circuited (see Table 4-3)
- Pin short-circuited to an adjacent pin (see Table 4-4)
- Pin short-circuited to supply (see Table 4-5)

Table 4-2 through Table 4-5 also indicate how these pin conditions can affect the device as per the failure effects classification in Table 4-1.

Class	Failure Effects	
A	Potential device damage that affects functionality	
В	No device damage, but loss of functionality	
C	No device damage, but performance degradation	
D	No device damage, no impact to functionality or performance	

Table 4-1. TI Classification of Failure Effects

Figure 4-1 shows the LM5158-Q1 and LM51581-Q1 pin diagram. For a detailed description of the device pins please refer to the *Pin Configuration and Functions* section in the LM5158-Q1 and LM51581-Q1 data sheet.

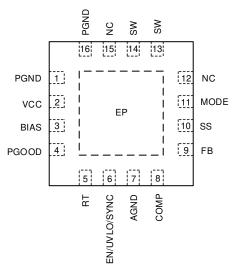


Figure 4-1. Pin Diagram

Following are the assumptions of use and the device configuration assumed for the pin FMA in this section:

- Device used within the *Recommended Operating Conditions* and the *Absolute Maximum Ratings* found in the LM5158-Q1 and LM51581-Q1 data sheet.
- Configuration as boost converter as shown in the Application and Implementation found in the LM5158-Q1 and LM51581-Q1 data sheet.

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
PGND	1, 16	No effect. Normal operation	D
VCC	2	VCC regulator short circuit. Device may shut down due to thermal shut down.	В
BIAS	3	Device unpowered. Device is not functional.	В
PGOOD	4	Correct output voltage. Loss of power good functionality	В
RT	5	Switching frequency increased to > 2.2 MHz. Device may be unstable.	В

Table 4-2. Pin FMA for Device Pins Short-Circuited to Ground

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Table 4-2. Pin FMA for Device Pins Short-Circuited to Ground (continued)

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
EN/UVLO/SYNC	6	EN stuck low. Device disabled and in shutdown mode.	В
AGND	7	No effect. Normal operation	D
COMP	8	Device out of regulation. Device is not switching.	В
FB	9	Output voltage rises and can exceed the absolute maximum rating of the SW pin voltage. Potential damage to pin	A
SS	10	During soft start, the SS pin stuck low. The device does not start up. The device stops switching during operation.	В
MODE	11	Hiccup mode protection is disabled and spread spectrum is disabled.	В
NC	12, 15	No effect. Normal operation	D
SW	13, 14	Potential damage to inductor and pin	A

Table 4-3. Pin FMA for Device Pins Open-Circuited

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
PGND	1, 16	Possible device damage	A
VCC	2	High ripple on VCC pin that can trigger VCC UVLO	В
BIAS	3	Device unpowered. Device is not functional.	В
PGOOD	4	Correct output voltage. Loss of power-good functionality	С
RT	5	Internal oscillator is instable or not functional. The device stops switching operation.	В
EN/UVLO/SYNC	6	State of EN/UVLO/SYNC undetermined. Device may be in shutdown or standby mode or enabled.	В
AGND	7	Possible device damage	A
COMP	8	Device may be unstable.	С
FB	9	Output voltage is out of regulation.	В
SS	10	During soft start, the SS pin pulled high. The device soft-start time is reduced to 0. High inrush current possible. No effect during operation	С
MODE	11	Hiccup mode protection is disabled and spread spectrum is enabled. No effect during operation	В
NC	12, 15	No effect. Normal operation	D
SW	13, 14	Output voltage is out of regulation. Output voltage is equal to the input voltage minus diode forward voltage drop.	В

Table 4-4. Pin FMA for Device Pins Short-Circuited to Adjacent Pin

Pin Name	Pin No.	Shorted to	Description of Potential Failure Effect(s)	Failure Effect Class
PGND	1	VCC	VCC regulator short circuit. Device may shut down due to thermal shutdown.	В
VCC	2	BIAS	Potential device damage if BIAS voltage is greater 5.8 V	А
BIAS	3	PGOOD	Potential device damage if BIAS voltage is greater 18 V	А
PGOOD	4	RT	Loss of power-good functionality. Switching frequency is wrong.	В
RT	5	EN/UVLO/SYNC	EN pin voltage at enable threshold. Device is either disabled and in shutdown mode or in standby mode.	В
EN/UVLO/SYNC	6	AGND	EN stuck low. Device is disabled and in shutdown mode.	В
AGND	7	COMP	Device out of regulation. Device is not switching.	В
COMP	8	FB	COMP and FB pin voltage clamped to 1 V. Device is not switching and out of regulation.	В
FB	9	SS	COMP pin voltage clamped to 1 V. Device is not switching and out of regulation.	В
SS	10	MODE	MODE pin pulled low during read out. Hiccup mode protection is disabled and spread spectrum is disabled.	В

Pin Name	Pin No.	Shorted to	Description of Potential Failure Effect(s)	Failure Effect Class
MODE	11	NC	No effect. Normal operation	D
NC	12	SW	No effect. Normal operation	D
SW	13	SW	No effect. Normal operation	D
SW	14	NC	No effect. Normal operation	D
NC	15	PGND	No effect. Normal operation	D
PGND	16	PGND	No effect. Normal operation	D

Table 4-4. Pin FMA for Device Pins Short-Circuited to Adjacent Pin (continued)

Table 4-5. Pin FMA for Device Pins Short-Circuited to BIAS supply

Pin Name	Pin No.	Description of Potential Failure Effect(s)	Failure Effect Class
PGND	1, 16	Device unpowered. Device not functional. Observe that the absolute maximum ratings for all pins of the device are met, otherwise device damage may be plausible.	А
VCC	2	Potential device damage if BIAS voltage is greater 5.8 V	A
BIAS	3	No effect. Normal operation	D
PGOOD	4	Potential device damage if BIAS voltage is greater 18 V	A
RT	5	Potential device damage if BIAS voltage is greater 3.8 V	A
EN/UVLO/SYNC	6	No effect. Normal operation	D
AGND	7	Device unpowered. Device is not functional. Observe that the absolute maximum ratings for all pins of the device are met, otherwise device damage may be plausible.	A
COMP	8	Potential device damage	A
FB	9	Potential device damage if BIAS voltage is greater 4.0 V	A
SS	10	Potential device damage if BIAS voltage is greater 3.8 V	A
MODE	11	Potential device damage if BIAS voltage is greater 3.8 V	A
NC	12, 15	No effect. Normal operation	D
SW	13, 14	Inductor out of regulation loop. Device is not functional.	В

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